Surface Analysis of Nanomaterials

(나노소재표면분석)

:Surface and Thin Film Analysis (표면 및 박막분석)

장소: 공과대학 6호관 510호

시간: 목 (1-A, 1-B, 2-A, 2-B, 3-A, 3-B)

Binding Energy and the Chemical Shift

Previous section

The general concept of the electron binding energy and its relationship to the energy of the incident X-ray and the emitted photoelectron was introduced

=> What the quantities that affect the E_B magnitude?

How measurement of the E_B can be used to characterize materials?

Chemical Shifts

depend on the bonding environment around the atom, in particular, on the oxidation state of the atom

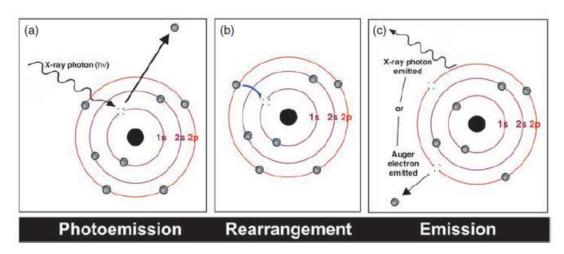
Binding Energy and the Chemical Shift

KOOPMANS' THEOREM

The E_B of an emitted photoelectron is simply the energy difference between the (n-1)-electron final state and the n-electron initial state (see below). This is written as:

$$E_{B} = E_{f}(n-1) - E_{i}(n)$$

where $E_{\rm f}(n-1)$ is the final state energy and $E_{\rm i}(n)$ is the initial state energy



(a) The X-ray photon transfers its energy to a core-level electron leading to photoemission from the n-electron initial state.

Binding Energy and the Chemical Shift

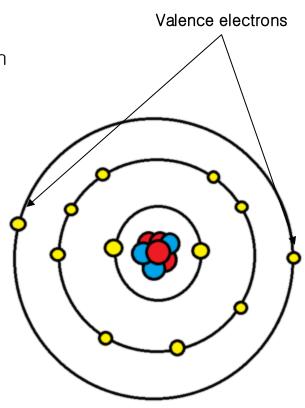
Valance and Core electron

Valence electrons are the electrons orbiting the nucleus in the outermost atomic shell of an atom.

Electrons that are closer to the nucleus are in filled orbitals and are called **core electrons**.

Valence electrons are the farthest from the positive charge (the protons) and thus tend to be easier to remove than core electrons; this means that it takes them less energy to move far away from the atom. This difference comes from the electric force being an inverse square law. Removing an electron (any of them) from a neutral atom turns the atom into an ion.

Valence electrons also tend to be the electrons that specifically participate in a chemical bond, like ionic bonds or covalent bonds.



core electrons

Binding Energy and the Chemical Shift

KOOPMANS' THEOREM

If no rearrangement of other electrons in the atom or material occurred during the photoemission process, then the observed $\mathcal{E}_{\mathbb{B}}$ would be just the negative orbital energy, $-\varepsilon_{\mathbb{K}}$ for the ejected photoelectron.

This approximation comes from <u>Koopmans' theorem</u> [22] and is written as:

$$E_{\rm B} \approx -\varepsilon_{\rm k}$$
 (3.3)

The values of \mathcal{E}_k can be calculated using the <u>Hartree-Fock method</u>.

The values of \mathcal{E}_{k} can be calculated using the Hartree-Fock method. These values are typically within 10-30 eV of the actual \mathcal{E}_{B} values.

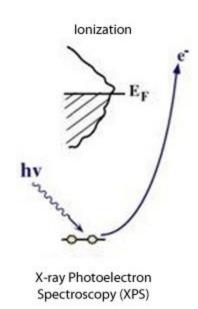
The disagreement between E_B and $-\varepsilon_K$ is because Koopmans' theorem and the Hartree-Fock calculation method do not provide a complete accounting of the quantities that contribute to E_B

Binding Energy and the Chemical Shift

KOOPMANS' THEOREM

In particular, the assumption that other electrons remain 'frozen' during the photoemission process is not valid.

During emission of the photoelectron, other electrons in the sample will respond to the creation of the core hole by rearranging to shield, or minimize, the energy of the ionized atom.



The energy reduction caused by this rearrangement of electrons is called the 'relaxation energy'

Relaxation occurs for both electrons on the atom containing the core hole (atomic relaxation) and on surrounding atoms (extra-atomic relaxation)

Binding Energy and the Chemical Shift

KOOPMANS' THEOREM

Relaxation is a final state effect and will be described in more detail later in this section. In addition to relaxation, quantities such as electron correlation and relativistic effects are neglected by the Koopmans/Hartree-Fock scheme. Thus, a more complete description of $E_{\rm B}$ is given by:

$$E_{\rm B} = -\varepsilon_{\rm k} - \varepsilon_{\rm r}(k) - \delta\varepsilon_{\rm corr} - \delta\varepsilon_{\rm rel}(3.4)$$

where E(k) is the <u>relaxation energy</u> and $\delta \varepsilon_{\text{corr}}$ and $\delta \varepsilon_{\text{rel}}$ are corrections for the differential <u>correlation</u> and <u>relativistic</u> energies.

-> Both the correlation and relativistic terms are typically small and usually can be neglected.

Binding Energy and the Chemical Shift

INITIAL STATE EFFECTS

Again

The E_B of an emitted photoelectron is simply the energy difference between the (n-1)-electron final state and the n-electron initial state (see below). This is written as:

$$E_B = E_f(n-1) - E_f(n)$$

=> both initial and final state effects contribute to the observed E_B.

the binding energy is equal to the difference in energies between the atom with n electrons [E(n)] and the ion with n-1 electrons [E(n-1)]

The initial state is just the ground state of the atom prior to the photoemission process

Binding Energy and the Chemical Shift

INITIAL STATE EFFECTS

If the energy of the atom's initial state is changed by formation of chemical bonds with other atoms, then the E of electrons in that atom will change.

The change in $E_{\mathbb{B}}$, $\Delta E_{\mathbb{B}}$, is called the chemical shift.

To a first approximation,

All core-level Es for an element will undergo the same chemical shift

<Example>

if a silicon atom is bound to a chlorine atom, i.e. a Si—Cl bond, the chemical shift for the Si_{2p} and Si_{2S} Si—Cl peaks relative to the position of the Si⁰ state for each peak will be similar.

Binding Energy and the Chemical Shift

INITIAL STATE EFFECTS

Initial state effects are responsible for the observed chemical shifts, as the formal oxidation state of an element increases, the E of photoelectrons ejected from that element will increase.

final state effects such as relaxation have similar magnitudes for different oxidation states.

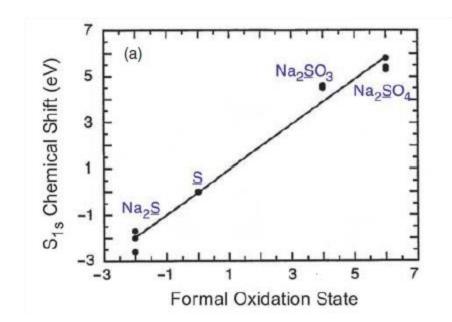
For most samples, the interpretation of E solely in terms of initial state effects

$$E_{\rm B} = - \triangle \varepsilon_{\rm k}$$

Binding Energy and the Chemical Shift

INITIAL STATE EFFECTS

Correlation between the initial state of an element and its $E_{\mathbb{B}}$



 E_B for the S_{1s} orbital increased by nearly 8 eV as the formal oxidation state of sulfur increased from -2 (Na₂S) to +6 (Na₂SO₄)

Binding Energy and the Chemical Shift

INITIAL STATE EFFECTS

Correlation between the initial state of an element and its $E_{\mathbb{R}}$

Functional group		Binding energy (eV)
Hydrocarbon	С—Н <u>,С</u> —С	285.0
Amine	C—N	286.0
Alcohol, ether	<u>C</u> —O—H, <u>C</u> —O—C	286.5
Cl bound to carbon	<u>C</u> —Cl	286.5
F bound to carbon	<u>C</u> —F	287.8
Carbonyl	<u>c</u> =0	288.0
Amide	O N— <u>C</u> =O	288.2
Acid, ester	0— <u>C</u> ≕0	289.0
Urea	N—C(=O)—N	289.0
Carbamate (urethane)	O-C(=O)-N	289.6
Carbonate	O-C(=O)-O	290.3
2F bound to carbon	$-CH_2CF_2-$	290.6
Carbon in PTFE	—CF ₂ CF ₂ —	292.0
3F bound to carbon	—CF ₃	293-294

[&]quot;The observed binding energies will depend on the specific environment where the functional groups are located. Most ranges are ± 0.2 eV, but some (e.g., fluorocarbon samples) can be larger.

Typical C_{1s} binding energies for organic samples

Binding Energy and the Chemical Shift

INITIAL STATE EFFECTS

Correlation between the initial state of an element and its $E_{\mathbb{B}}$

Functional group		Binding energy (eV)
Carbonyl	C= <u>0</u> , O-C= <u>0</u>	532.2
Alcohol, ether	C- <u>0</u> -H, C- <u>0</u> -C	532.8
Ester	C- <u>0</u> -C=0	533.7

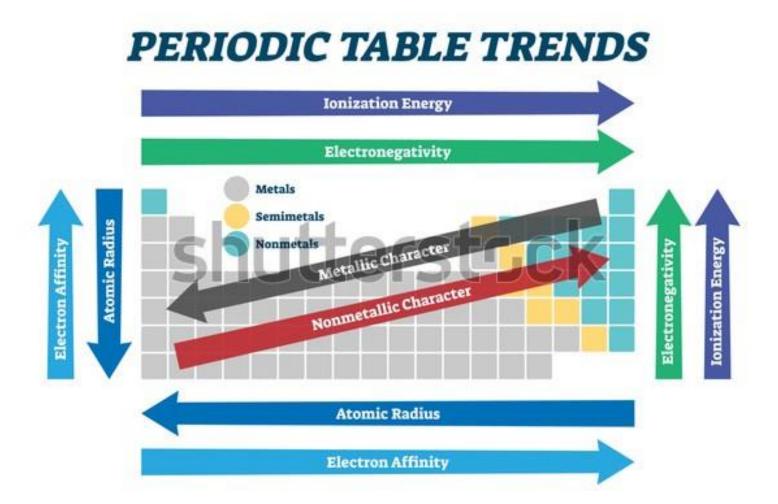
^aThe observed binding energies will depend on the specific environment where the functional groups are located. Most ranges are $\pm 0.2 \, \text{eV}$.

Typical O_{1s} binding energies for organic samples

The C_{1s} E_{1s} is observed to increase monotonically <u>as the number of oxygen atoms</u> bonded to carbon increases (C-C < C-O < C-O < O-C-O < O-(C-O)O-) since oxygen is more electronegative than carbon and will draw electrons away from carbon.

This is consistent with an initial state effect, since, as the number of oxygen atoms bonded to a carbon increase, the carbon should become more positively charged, resulting in an increase in the $C_{1s} E_{B}$.

Electronegativity (전기음성도)



Binding Energy and the Chemical Shift

INITIAL STATE EFFECTS

A caution must be made against solely using initial state effects for interpreting chemical shifts. There are examples where final state effects can significantly alter the relationship between the formal oxidation state and \mathcal{E}_{B} .

Also, it is the changes in the distribution and density of electrons of an atom resulting from changes in its chemical environment that contribute to $\mathcal{E}_{\mathbb{B}}$.

These quantities do not necessarily have a straightforward relationship to the formal oxidation state.

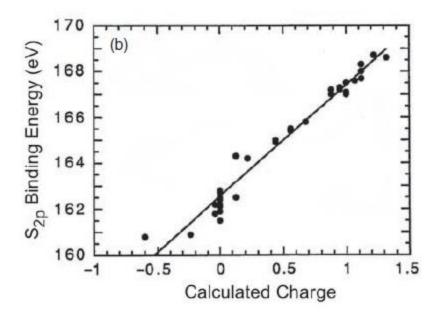
For example, the full charge implied by the formal oxidation state is only attained when the chemical bonding is completely ionic (no covalent character). The degree of ionic/covalent character can vary with the chemical environment.

Thus, it is best to correlate E with the charge on the atom, not its formal oxidation state.

Binding Energy and the Chemical Shift

Consistent correlations for both inorganic and organic sulfur species

Linear relationship they observed for the S_2 , E_B versus calculated charge on the sulfur atom



The sulfur 2p binding energy versus calculated charge for several inorganic and organic sulfur species.

Binding Energy and the Chemical Shift

Charge potential model

This model relates the observed E_B to a reference energy E^0_B , the charge q_i on atom i, and the charge q_i on the surrounding atoms j at distances r_{ij} as follows:

$$E_{\mathrm{B}} = E_{\mathrm{B}}^{\circ} + kq_{i} + \sum_{j \neq i} (q_{j}/r_{ij})$$

with the constant k. Generally, the reference state is considered to be \mathcal{E}_{B} for the neutral atom.

It is then apparent that, as the positive charge on the atom increases by formation of chemical bonds, E_B will increase.

<u>Madelung potential</u> because of its similarity to the lattice potential of a crystal, $V_i = \sum g_i/r_i$.

This term represents the fact that the charge q_i removed or added by formation of a chemical bond is not displaced to infinity, but rather to the surrounding atoms.

Binding Energy and the Chemical Shift

Charge potential model

Using following Equation
$$E_{\rm B} = E_{\rm B}^{\circ} + kq_i + \sum_{j \neq i} (q_j/r_{ij})$$

chemical shift between states 1 and 2 can now be written as:

$$\Delta E_{\rm B} = k[q_i(2) - q_i(1)] + V_i(2) - V_i(1)$$

$$\Delta E_{\rm B} = k\Delta q_i + \Delta V_i$$

where ΔV_i the potential change in the surrounding atoms

Binding Energy and the Chemical Shift

FINAL STATE EFFECTS

<u>Relaxation effects</u> can have a significant impact on the measured E_B . In all cases the electron rearrangements that occur during photoemission result in the lowering of E_B .

If the magnitude of the relaxation energy varies significantly as the chemical environment of an atom is changed, the $E_{\rm B}$ ranking that would be expected based on initial state considerations, can be altered

the ranking of the Co
$$2p_{3/2}$$
 E_B values
$$Co^0 (778.2 \, eV) < Co^{+3} (779.6 \, eV) < Co^{2+} (780.5 \, eV)$$

Binding Energy and the Chemical Shift

FINAL STATE EFFECTS

For Copper

both Cu⁰ and Cu⁺¹ have $2p_{3/2}EB$ values of 932.5 eV ($E_B = 0$)

=> for the Co and Cu systems, <u>final state effects cause deviations</u> in the E_B versus oxidation state ranking expected from initial state considerations

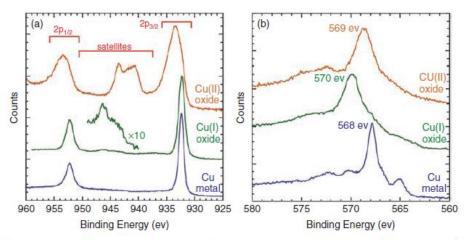


Figure 3.4 (a) The copper 2p photoemission spectra for metallic Cu (Cu^0) , Cu₂O (Cu^{+1}) and CuO (Cu^{+2}) . (b) The X-ray induced copper Auger LVV spectra for metallic Cu (Cu^0) , Cu₂O (Cu^{+1}) and CuO (Cu^{+2})

Binding Energy and the Chemical Shift

FINAL STATE EFFECTS

Contributions to the relaxation energy arise from both the atom containing the core hole (atomic relaxation) and its surrounding atoms (extra-atomic relaxation).

Most of the <u>atomic relaxation component</u> results from <u>rearrangement of outer</u> shell electrons, which have a smaller E_B than the emitted photoelectron.

In contrast, the <u>inner shell electrons</u> (E_B larger than the emitted photoelectron) make only a small contribution to the atomic relaxation energy and can <u>usually</u> <u>be neglected</u>.

For electrically conducting samples such as metals, valence band electrons can move from one atom to the next to screen the core hole.

For ionically bonded solids such as the alkali halides, electrons are not free to move from one atom to the next

Binding Energy and the Chemical Shift

FINAL STATE EFFECTS

Other types of final state effects such as <u>multiplet splitting</u> and <u>shake-up</u> satellites can contribute to E_B .

Multiplet splitting

arises from interaction of the core hole with unpaired electrons in the outer shell orbitals

Shake-up

satellites arise from the outgoing photoelectron losing part of its kinetic energy to excite a valence electron into an unoccupied orbital (e.g. $\pi \to \pi^*$ transition).

Binding Energy Referencing

 \mathcal{E}_{B} is determined by measuring the KE of the emitted photoelectron

-> a calibrated and suitably referenced ESCA spectrometer is required!

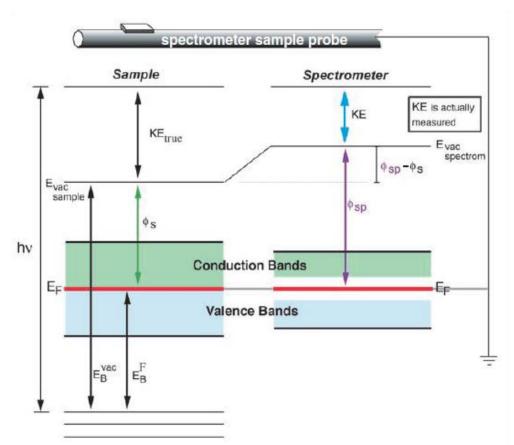
How to set up an ESCA spectrometer to measure accurately the photoelectron KE (and therefore $E_{\rm B}$) for different types of samples.

Conducting samples

metals are placed in electrical contact with the spectrometer, typically by grounding both the sample and the spectrometer.

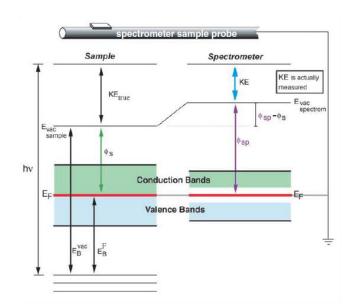
This puts the Fermi level (E_F), the highest occupied energy level, of both the sample and spectrometer, at the same energy level.

Binding Energy Referencing



This puts the Fermi level (E_F), the highest occupied energy level, of both the sample and spectrometer, at the same energy level. Then the photoelectron KE can be measured

Binding Energy Referencing



The sum of the KE and E_B does not exactly equal the X-ray energy

The difference is the <u>work function of the</u> spectrometer (ϕ_{sp})

The work function, ϕ , is related to the E_F and vacuum level (E_{vac}) by:

$$\phi = E_{\rm F} - E_{\rm vac}$$

 ϕ is the minimum energy required to eject an electron from the highest occupied level into vacuum. The Einstein equation now becomes:

$$E_{\rm B}^{\rm F} = h \nu - {\rm KE} - \phi_{\rm sp}$$

both KE and ϕ_{sp} must be measured to determine E_B . The superscript F on E_B means that E_B is referenced to E_F .

Binding Energy Referencing

Calibration for conducting samples

The work function of the spectrometer (ϕ_{sp}) that is important

Can be calibrated by placing a clean Au standard in the spectrometer and adjusting the instrumental settings such that the known E_B values for Au are obtained (e.g. E_F = 0 eV, $4f_{7/2}$ = 83.96 eV).

The linearity of the $E_{\rm B}$ scale is then calibrated by adjusting the energy difference between two widely spaced lines of a sample (e.g. the 3s and $2p_{3/2}$ peaks of clean Cu) to their known values.

ISO Standard 15472:2001 https://www.iso.org/standard/55796.html
Surface chemical analysis — X-ray photoelectron
spectrometers — Calibration of energy scales

Binding Energy Referencing

Validity of Calibration

Once the spectrometer energy scale has been calibrated, it is assumed to remain constant.

This is valid as long as the spectrometer is maintained in an UHV environment.

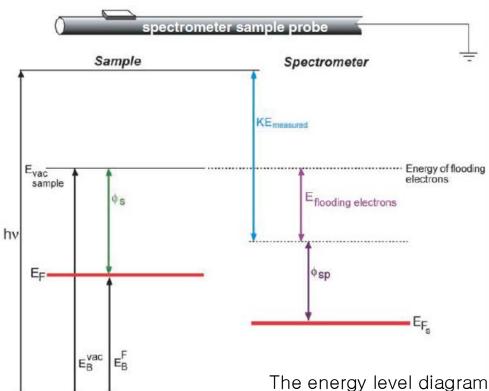
If the pressure of the spectrometer is raised above the UHV range, particularly when exposed to a reactive gas, different species can adsorb to components in the analyzer.

This will change the ϕ_{sp} and necessitate recalibration.

It is always good practice to regularly (i.e., daily to weekly) check the instrument calibration.

Charge Compensation in insulators

When some materials do not have sufficient electrical conductivity or cannot be mounted in electrical contact with the ESCA spectrometer.



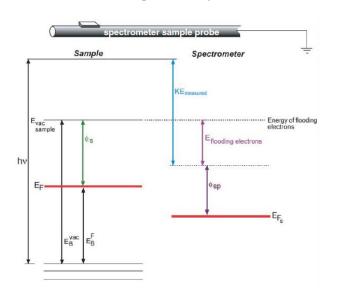
The energy level diagram for a <u>sample electrically insulated from</u> the <u>spectrometer</u>. The vacuum level of the sample ($\mathcal{E}^s_{\text{vac}}$) is aligned with the energy of the charge neutralization electrons (ϕ_s) so that \mathcal{E}_B is referenced with respect to ϕ_s . The measurement of \mathcal{E}_B is dependent on the sample work function, ϕ_s

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Charge Compensation in insulators

Insulating samples



the measured $E_{\rm B}$ of an insulated sample depends on its work function ($\phi_{\rm s}$) and the energy of the flooding electrons, $\phi_{\rm e}$,

$$E_{\rm B}^{\rm vac} = E_{\rm B}^{\rm F} + \phi_{\rm s} = h\nu - {\rm KE} + \phi_{\rm e}$$

for insulators $E_{\rm B}$ is referenced to $E_{\rm vac}$ and $\phi_{\rm e}$.

This makes it difficult or impossible to measure absolute E_B values for samples not in electrical contact with the spectrometer.

For polymer and organic samples, the hydrocarbon component (C-C/C-H) of the C1s peak is typically set to 285.0 eV.

For supported catalysts, a major peak of the oxide support (Si_{2p}, Al_{2p}, etc.) is typically used.

Internal referencing of the E_B scale allows the accurate measurement of other E_B values in the sample.

Charge Compensation in insulators

Effect of flooding electrons

Usually the energy of the flooding electrons is varied to obtain the narrowest width of the photoemission peak

→ It is important to have the entire sample either electrically grounded or fully isolated!!

A sample in <u>partial electrical contact with the spectrometer</u> can lead to <u>differential charging</u>, which will produce <u>distorted peak shapes</u> and, under extreme conditions, new peaks

Must be aware of the electrical properties of the sample and how they can affect the ESCA experiment.

Charge Compensation in insulators

Effect of flooding electrons

Example

a conducting metal substrate with a <u>thin (\sim 5nm or less) insulating overlayer</u> can usually be analyzed with the sample grounded.

However, if the <u>insulating overlayer</u> becomes too thick (~ 10 nm or more), differential charging can occur.

Then the entire sample must be electrically isolated from the spectrometer for proper analysis.

For samples with <u>electrical properties that vary with location on the sample</u>, carefully designed experiments can be used to gain further information about <u>the electrical and spatial properties of a sample</u>

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